SIEMENS

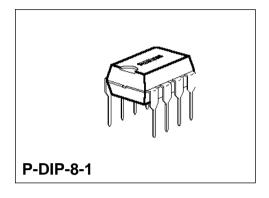
Proximity Switch

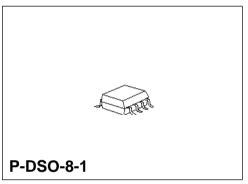
TCA 305 TCA 355

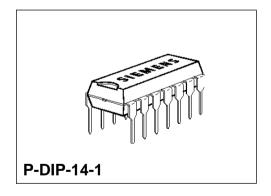
Bipolar IC

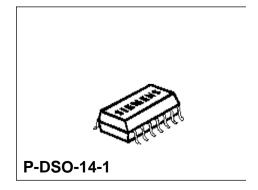
Features

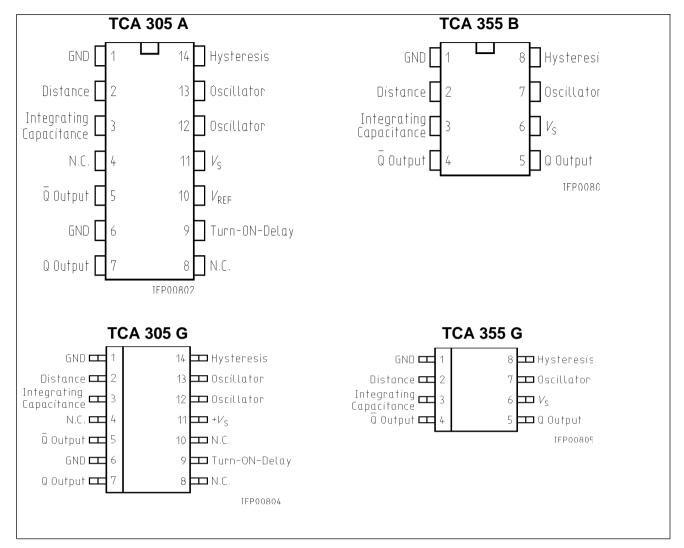
- Lower open-loop current consumption; I_S < 1 mA
- Lower output saturation voltage
- The temperature dependence of the switching distance is lower and compensation of the resonant circuit TC (temperature coefficient) is easier
- The sensitivity is higher, so that larger switching distances are possible and coils of a lower quality can be used
- The switching hysteresis remains constant as regards temperature, supply voltage and switching distance
- The TCA 305 even functions without external integrating capacitor. With an external capacitor (or with RC combination) good noise immunity can be achieved
- The outputs are temporarily short-circuit proof (approx.
 10 s to 1 min depending on package)
- The outputs are disabled when Vs < approx. 4.5 V and are enabled when the oscillator stabilizes (from Vs min = 5 V)
- Higher switching frequencies can be obtained
- Miniature package











Pin Configurations (top view)

The devices TCA 305 and TCA 355 contain all the functions necessary to design inductive proximity switches. By approaching a standard metal plate to the coil, the resonant circuit is damped and the outputs are switched.

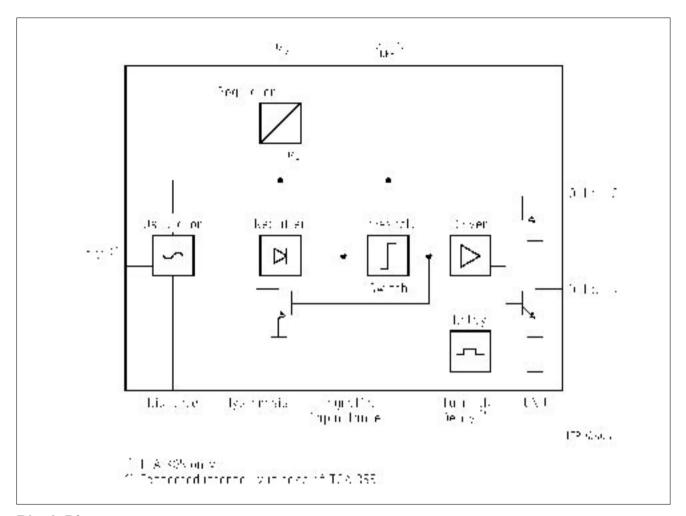
Operation Schematic: see TCA 205

The types TCA 305 and TCA 355 have been developed from the type TCA 205 and are outstanding for the following characteristics:

Logic Functions

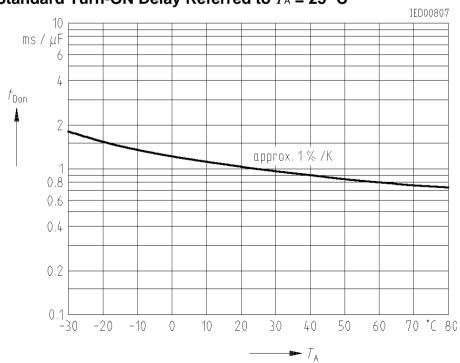
Oscillator	Outpo	Outputs	
	Q		
not damped	Н	L	
damped	L	Н	





Block Diagram

Standard Turn-ON Delay Referred to T_A = 25 °C



Absolute Maximum Ratings

Parameter	Symbol	Limit Values	Unit
Supply voltage	<i>V</i> s	35	V
Output voltage	V_{Q}	35	V
Output current	IQ	50	mA
Distance, hysteresis resistance	RDi, R Hy	0	Ω
Capacitances	<i>C</i> ı, <i>C</i> D	5	μF
Junction temperature	T _j	150	°C
Storage temperature range	$T_{ m stg}$	- 55 to 125	°C
Thermal resistance			
system - air TCA 305 A	Rth SA	85 (135) ²⁾	K/W
TCA 305 G	$oldsymbol{R}$ th SA	140 (200)2)	K/W

Operating Range

Supply voltage	<i>V</i> s	5 to 30 ³⁾	V
Oscillator frequency	<i>f</i> osc	0.015 to 1.5	MHz
Ambient temperature	T_{A}	- 25 to 85	°C

Characteristics

 $V_{\rm S} = 12 \text{ V}, T_{\rm A} = -25 \text{ to } 85 \,^{\circ}\text{C}$

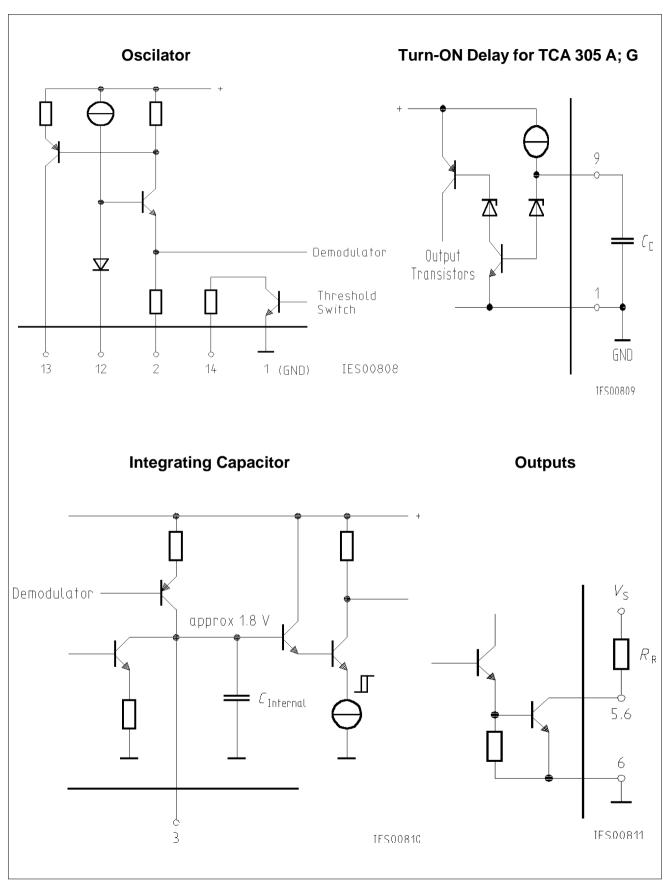
Parameter	Symbol		Limit Values			Test
		min.	typ.	max.		Condition
Open-loop current consumption	<i>I</i> s		0.6	0.9 (1.0) ²⁾	mA	outputs open
Reference voltage ¹⁾ L-output voltage per output	VREF VQL VQL VQL		3.2 0.04 0.10 0.22	0.15 0.35 0.75	V V V	I_{REF} < 10 μ A I_{QL} = 5 mA I_{QL} = 25 mA I_{QL} = 50 mA
H-output current per output	<i>I</i> Q H			10	μΑ	<i>V</i> Qн = 30 V
Threshold at 3 Hysteresis at 3	VS 3 V Hy	0.4	2.1 0.5	0.6	V V	
Turn-ON delay ¹⁾	td on	– 25 %	600	– 25 %	ms/μF	<i>T</i> _A = 25 °C
Switching frequency w/o Cı	Æ			5	kHz	

¹⁾ TCA 305 only

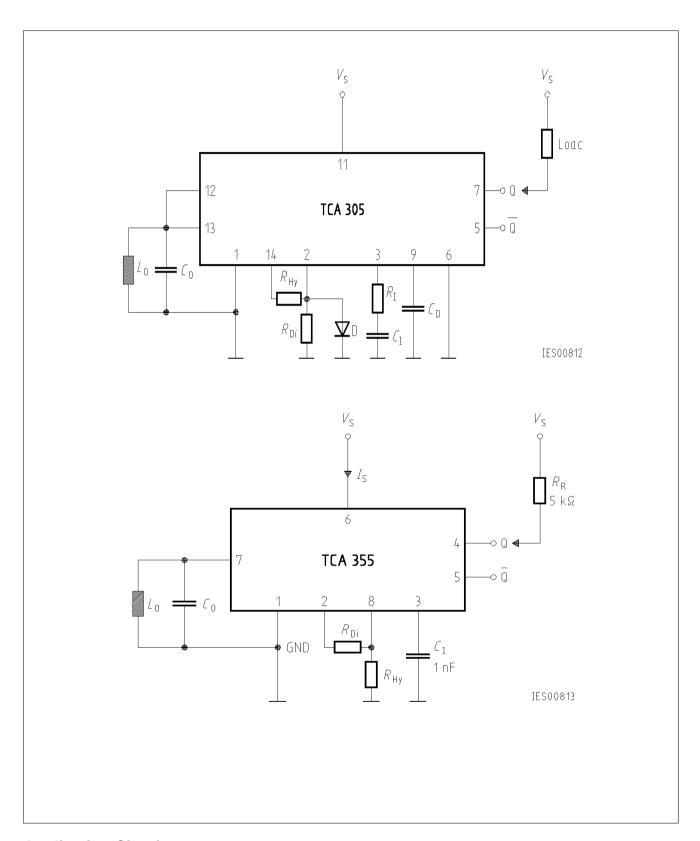
²⁾ Values in parenthesis apply to TCA 355 only

Operation at voltages less than 5 V (between approx. 2.5 and 5 V) is possible, if $V_{\rm REF}$ is connected to $V_{\rm S}$. In this case $V_{\rm REF}$ is no longer internally stabilized. Additionally, the pin "turn-on delay" is to be applied as follows: If no turn-on delay is needed, this pin has to be connected to $V_{\rm S}$. If, however, a turn-on delay is required, the charge current for $D_{\rm D}$ has to be adjusted with an external resistor between this pin and $V_{\rm S}$ (recommended value 390 k¹²).

SIEMENS



Schematic Circuit Diagram



Application Circuit

Lo, Co Resonant circuit
 RHy
 Hysteresis adjustment
 RDi
 Distance adjustment

D Temperature compensation of the resonant circuit; possibly with series resistance for the purpose of adjustment. The diode is not absolutely necessary. Whether it is used or not depends on the temperature coefficient of the resonant

circuit.

 R_1 ; C_1 Integration element. At pin 3 (integrating capacitance) we recommend a

capacitor of typ. 1 nF. To increase noise immunity this capacitor can be

substituted by an RC circuit with, e.g., $R_1 = 1 \text{ M}^{3.2}$ and $C_1 = 10 \text{ nF}$.

*C*_D Delay capacitor

Dimensioning Examples in Accordance with CENELEC Standard (flush)

	M 12	M 18	M 30
Ferrite pot core	M 33 (7.35 × 3.6) mm	N 22 (14.4 × 7.5) mm	N 22 (25 × 8.9) mm
Number of turns	100	80	100
Cross section of wire	0.1 CuL	20 × 0.05	10 × 0.1
L0	206 μΗ	268 μΗ	585 μH
C_0 (STYROFLEX®)	1000 pF	1.2 nF	3.3 nF
<i>f</i> osc	appr. 350 kHz	appr. 280 kHz	appr. 115 kHz
Sn	4 mm	8 mm	15 mm
R_A (Metal)	8.2 k ¹ + 330 ¹	33 k ₇₅	22 k ₇ + 2.7 k ₇
CD	100 nF	100 nF	100 nF